

**Session Program**

**25-28 Jun 2006**

**8th RD50 Workshop**

***Defect and Material Characterization***

Prague

# Monday 26 June

09:20

## Defect and Material Characterization

Session | Location: Prague

09:20–09:40

### Defect kinetics in Epi/Cz silicon after Co60-gamma irradiation

**Speaker**

Ioana Pintilie

09:40–10:00

### Characterization of irradiated silicon structures by microwave absorption techniques

**Speaker**

Eugenijus Gaubas

10:00–10:30

### Coffee break

10:30–10:50

### DLTS measurements of Epitaxial and MCZ silicon detectors after 26 MeV proton irradiation

**Speaker**

Frank Hoeniger

10:50–11:20

### Discussion on Defect and Material Characterization

11:20